

SPECIFICATION

Device Name : SILICON DIODE

Type Name : ESAF92-03R

Spec. No. : MS5D4271

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	DATE	NAME	APPROVED	Fuji Electric Co.,Ltd.		
DRAWN	Oct.-07-'14	<i>M. Shinose</i>	<i>J.</i> <i>Tada</i>	DWG.NO.	MS5D4271	
CHECKED	Oct.-07-'14	<i>T. Watanabe</i>				1/12
CHECKED	Oct.-07-'14	<i>J. Hasegawa</i>				

1. SCOPE

This specification provides the ratings and the test requirement for FUJI SILICON DIODE ESAF92-03RQ-P.

2. TYPE NAME, ORDERING TYPE NAME, COUNTRY CODE, PACKAGING ASSEMBLY LOCATION

Type name	Ordering type name	Country code	Packaging assembly location
ESAF92-03RQ-P	ESAF92-03RQ-P	P	Philippines

3. TYPE NAME, OUT VIEW-MARKING, MOLDING RESIN, CHARACTERISTICS

Ordering type name	Package type	Out view-Marking	Molding resin	Characteristics
ESAF92-03RQ-P	TO-3P	Page 9/12	UL:V-0	Page 10/12~12/12

Bar code label is EIAJ C-3 specification. Indispensable description items are shown as below.

- (1) Type name (2) Production code (3) Quantity
(4) Lot No.(Date code) (5) Company code

4. RATINGS

4.1 MAXIMUM RATINGS (at Ta=25°C unless otherwise specified.)

Item	Symbol	Conditions	Ratings	Units
Repetitive peak reverse voltage	V_{RRM}		300	V
Average forward current	I_o	50Hz Sine wave duty =1/2 Tc=86°C	60 *	A
Non-repetitive forward surge current **	I_{FSM}	Sine wave, 10ms 1shot	240	A
Operating junction temperature	Tj		150	°C
Storage temperature	Tstg		-55~+150	°C

* Out put current of center tap full wave connection.
**Rating per element

4.2 ELECTRICAL CHARACTERISTICS (at Ta=25°C unless otherwise specified.)

Item	Symbol	Conditions	Min.	Max.	Units
Forward voltage ***	V_F	$I_F = 30 A$	0.85	1.20	V
Reverse current ***	I_R	$V_R = V_{RRM}$	-	0.6	mA
Reverse recovery time ***	Trr	$I_F=0.1A, I_R=0.2A, I_{rec}=0.05A$	10	40	ns
Thermal resistance	Rth(j-c)	Junction to case	-	0.75	°C/W

*** Rating per element

4.3 MECHANICAL CHARACTERISTICS

Mounting torque	Recommended torque	0.4~0.6	N·m
Approximate mass		5.5	g

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5. TEST AND INSPECTION

5.1 STANDARD TEST CONDITION

Standard test condition is Ta=25°C, 65%R.H.

If judgment is no doubt, the test condition is possible to test in normal condition

Ta=5~35°C、48~85%R.H.

5.2 STRUCTURE INSPECTION

It inspect with eye and measure, Item 3 shall be satisfied.

5.3 FORWARD AND REVERSE CHARACTERISTICS

It inspect on the standard condition, Item 4.2 shall be satisfied.

5.4 TEST

	Test No.	Test items	Testing methods and conditions	Reference standard EIAJ ED4701	Sampling number	Acceptance number
Mechanical test	1	Terminal strength (Tensile)	Pull force : 25N Force maintaining duration : 10±1s	EIAJ ED4701/401 method 1	5	(0 : 1)
	2	Terminal strength (Bending)	Load force : 10N Number of times : 2times(90deg./time)	EIAJ ED4701/401 method 3	5	
	3	Mounting strength	Screwing torque value:(M3) : 50±10N·cm	EIAJ ED4701/402 method 2	5	
	4	Vibration	Frequency : 100Hz to 2kHz Acceleration : 200m/s ² Sweeping time : 4min./1 cycle 4times for each X, Y&Z directions.	EIAJ ED4701/403 test code D	5	
	5	Shock	Peak amplitude : 15km/s ² Duration time : 0.5ms 3times for each X, Y&Z directions.	EIAJ ED4701/404 test code D	5	
	6	Solderability 1	Solder : Sn-37Pb Solder temp. : 235±5°C Immersion time : 5±0.5s Apply to flux	EIAJ ED4701/303 test code A	5	
		Solderability 2	Solder : Sn-3Ag-0.5Cu Solder temp. : 245±5°C Immersion time : 5±0.5s Apply to flux	—	5	
7	Resistance to soldering heat	Solder temp. : 260±5°C Immersion time : 10±1s Number of times : 1time	EIAJ ED4701/302 test code A	5		

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Test No.	Test items	Testing methods and conditions	Reference standard EIAJ ED4701	Sampling number	Acceptance number
Endurance test	1	High temp. storage	Temperature : Tstg max Test duration : 1000h	EIAJ ED4701/201	22
	2	Low temp. storage	Temperature : Tstg min Test duration : 1000h	EIAJ ED4701/202	22
	3	Temperature humidity storage	Temperature : $85 \pm 2^\circ\text{C}$ Relative humidity : $85 \pm 5\%$ Test duration : 1000h	EIAJ ED4701/103 test code C	22
	4	Temperature humidity bias	Temperature : $85 \pm 2^\circ\text{C}$ Relative humidity : $85 \pm 5\%$ Bias voltage : $V_{RRM} \times 0.8$ Test duration : 1000h	EIAJ ED4701/102 test code C	22
	5	Unsaturated pressurized vapor	Temperature : $130 \pm 2^\circ\text{C}$ Relative humidity : $85 \pm 5\%$ Vapor pressure : 230kPa Test duration : 48h	EIAJ ED4701/102 test code F	22
	6	Temperature cycle	High temp. side : Tstg max Room temp. : $5 \sim 35^\circ\text{C}$ Low temp. side : Tstg min Duration time : HT 30min, RT 5min LT 30min Number of cycles : 100 cycles	EIAJ ED4701/105	22
	7	Thermal shock	Fluid : pure water(running water) High temp. side : $100+0/-5^\circ\text{C}$ Low temp. side : $0+5/-0^\circ\text{C}$ Duration time : HT 5min, LT 5min Number of cycles : 100 cycles	EIAJ ED4701/307 test code A	22
	8	Intermittent operating life	$T_j = T_{jmax} \sim 50^\circ\text{C}$ 3min ON, 3min OFF Number of cycles : 10000cycles	EIAJ ED4701/106	22
	9	High temp. reverse bias	Temperature : $T_a = 100^\circ\text{C}$ Bias voltage : $V_R = V_{RRM}$ DC Test duration : 1000h	EIAJ ED4701/101	22

(0 : 1)

Failure criteria	$I_R \leq \text{USL} \times 5$
	$V_F \leq \text{USL} \times 1.1$

USL : Upper specification limit

INSTALLATION

- Soldering involves temperatures which exceed the device storage temperature rating. To avoid device damage and to ensure reliability, observe the following guidelines from the quality assurance standard.

Solder temperature and duration

Method	Solder temperature	Duration
Flow	260±5°C	10±1sec
Soldering iron	350±10°C	3.5±0.5sec

- The immersion depth of the lead should basically be up to the lead stopper and the distance should be a maximum of 1.5mm from the device.
- When flow-soldering, be careful to avoid immersing the package in the solder bath.
- Refer to the following torque reference When mounting the device on a heat sink. Excess torque applied to the mounting screw causes damage to the device and weak torque will increase the thermal resistance, both of which conditions may destroy the device.

Recommended tightening torque

Package style	Screw	Recommended tightening torque
TO-3P	M3	0.4~0.6N·m

- The heat sink should have a flatness within ±30µm and roughness within 10µm. Also, keep the tightening torque within the limits of this specification.
- Improper handling may cause isolation breakdown leading to a critical accident.
- We recommend the use of thermal compound to optimize the efficiency of heat radiation. It is important to evenly apply the compound and to eliminate any air voids.

STORAGE

- The Diodes must be stored at a standard temperature of 5 to 35°C and relative humidity of 45 to 75%.
- The Diodes should not be subjected to rapid changes in temperature to avoid condensation on the surface of the Diodes. Therefore, store the Diodes in a place where the temperature is steady.
- The Diodes should not be stored on top of each other, since this may cause excessive external force on the case.
- The Diodes should not be stored with the lead terminals remaining unprocessed. Rust may cause presoldered connections to go fail during later processing.
- The Diodes should be stored in antistatic containers or shipping bags.

8. APPENDIX

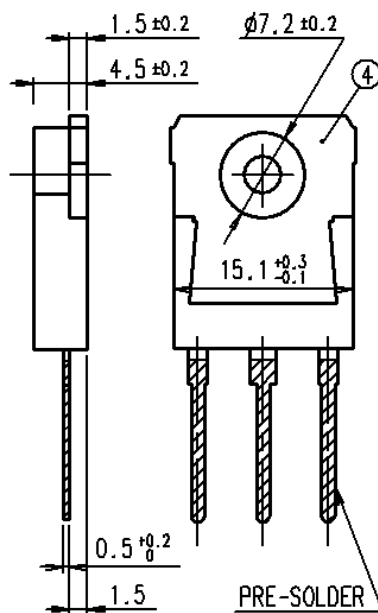
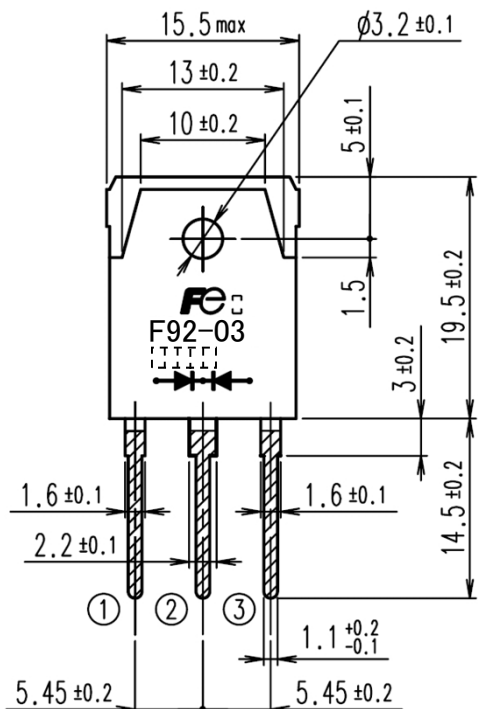
- This products does not contain PBBs (Polybrominated Biphenyl) or PBDEs (Polybrominated Diphenyl Ether) , substances.
- This products does not contain Class-I ODS and Class-II ODS substances set force by 'Clean Air Act of US' law.

- If you have any questions about any part of this specification, please contact Fuji Electric or its sales agent before using the product.
- Neither Fuji nor its agents shall be held liable for any injury caused by using the products not in accordance with the instructions.
- This specification does not confer any industrial property rights or other rights, nor constitute a license for such rights.

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TYPE : ESAF92-03RQ-P

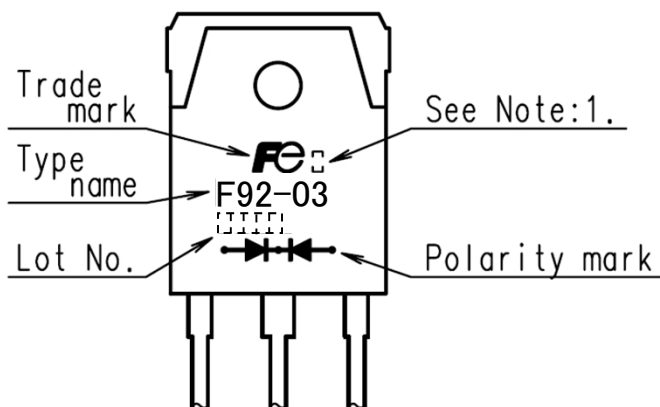
OUT VIEW



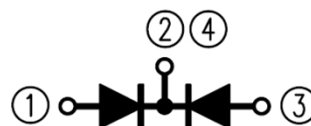
PRE-SOLDER
予備はんだ

Sn-Cu (Pb < 1000ppm)

(a) MARKING



CONNECTION

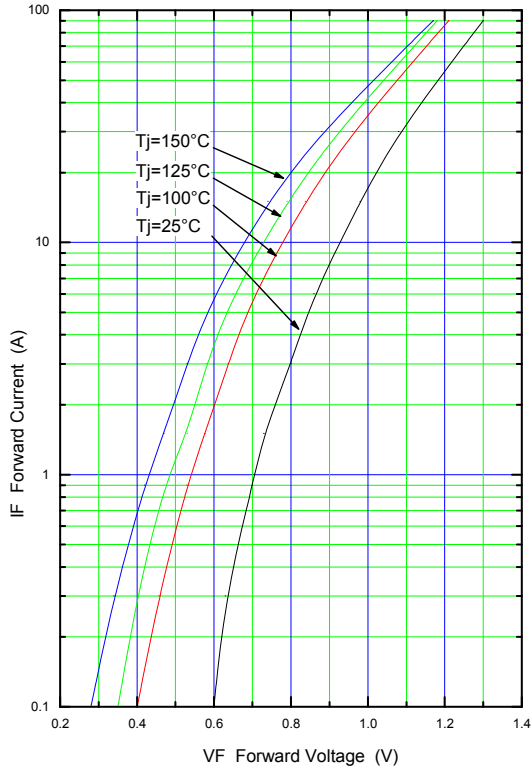


Note:1.
Country of origin mark.
No mark is Made in JAPAN.
『P』 is Made in PHILIPPINES.

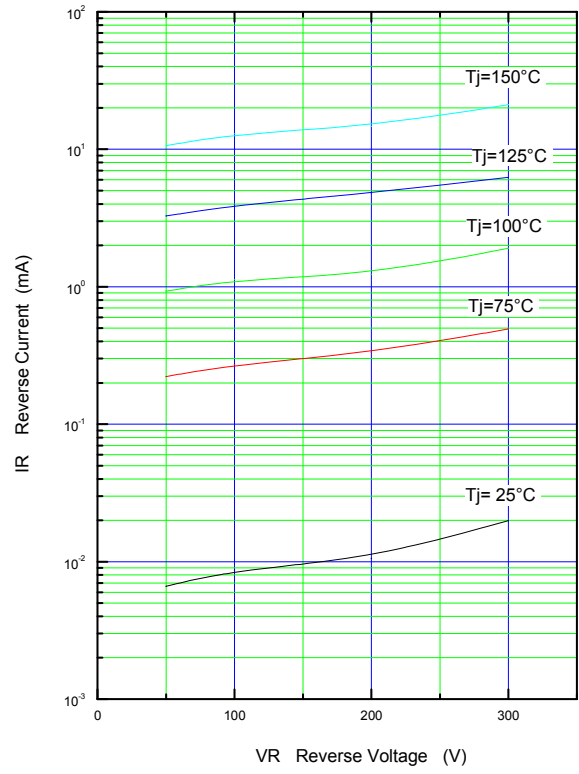
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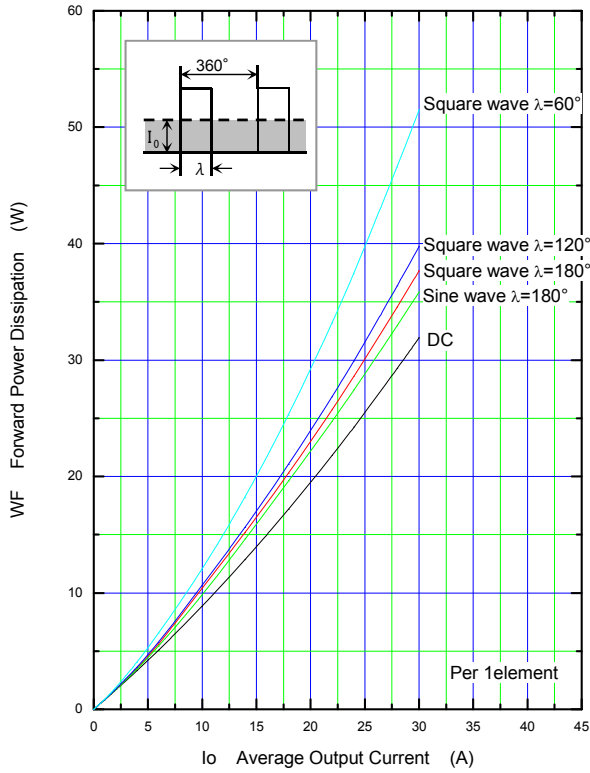
Forward Characteristic (typ.)



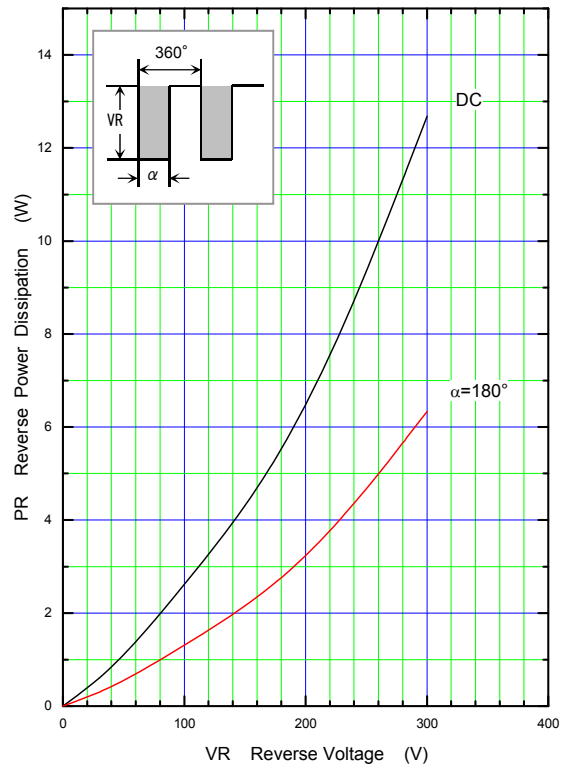
Reverse Characteristic (typ.)



Forward Power Dissipation (max.)

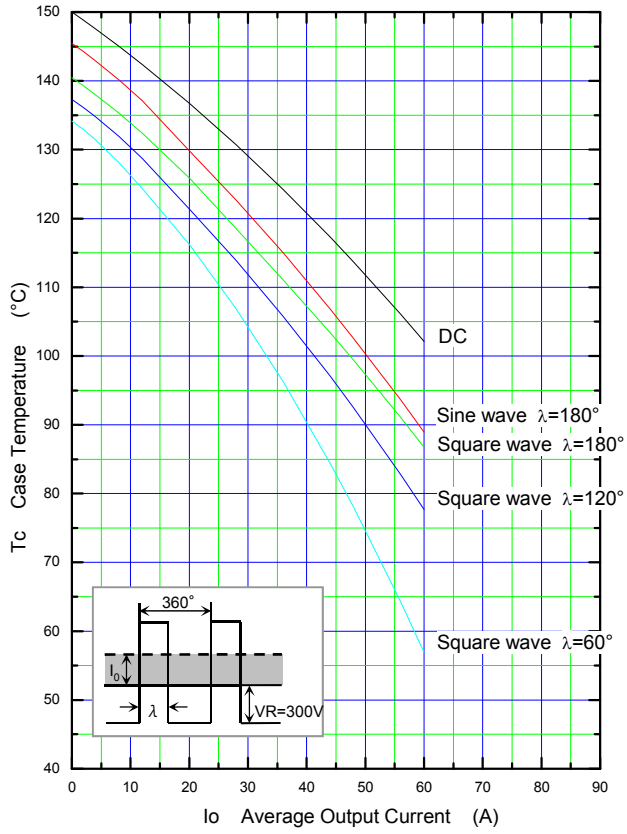


Reverse Power Dissipation (max.)



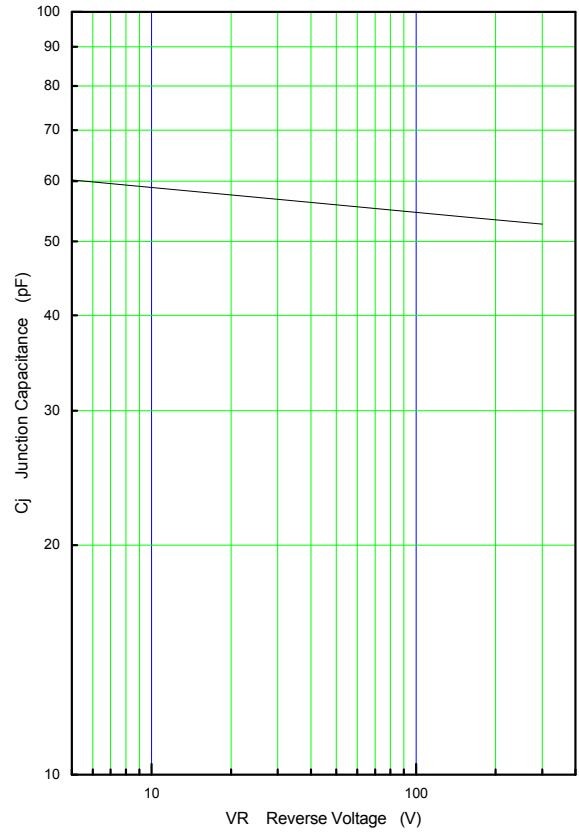
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Current Derating (I_o - T_c) (max.)

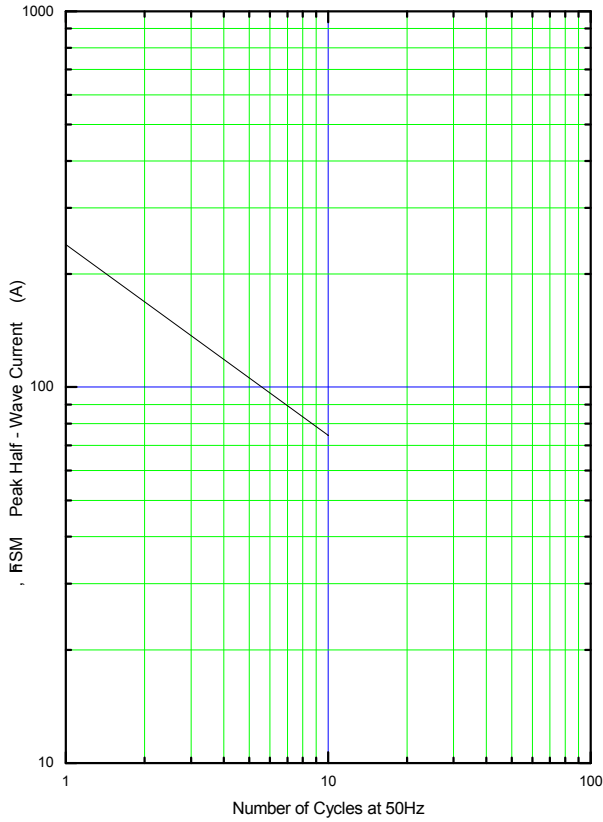


λ : Conduction angle of forward current for each rectifier element
 I_o : Output current of center-tap full wave connection

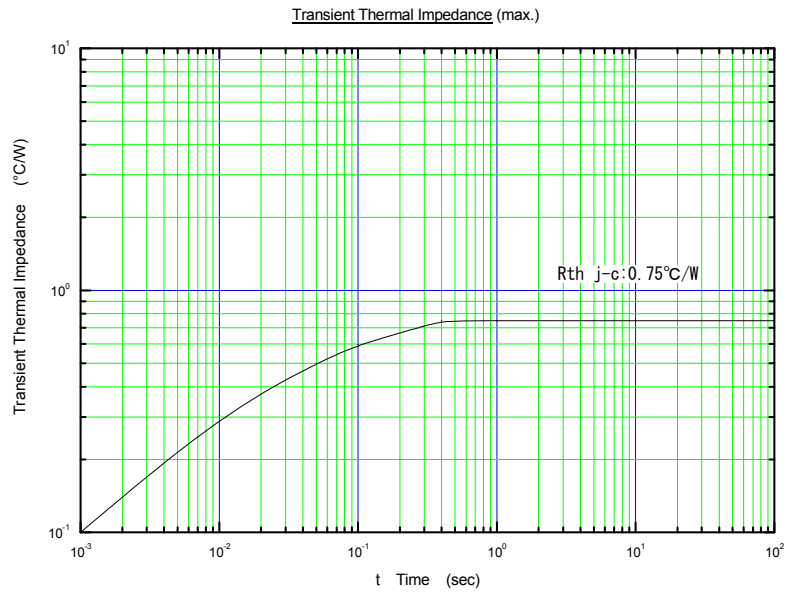
Junction Capacitance Characteristic (typ.)



Surge Capability (max.)



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